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# HD74HC442/HD74HC443/HC74HC444

Quad. Tridirectional Bus Transceiver  
(with noninverted 3-state outputs)

Quad. Tridirectional Bus Transceiver  
(with inverted 3-state outputs)

Quad Tridirectional Bus Transceiver  
(with noninverted/inverted 3-state outputs)

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### Description

These bus transceivers are designed for a synchronous three-way communication between four-line data buses. They give the designer a choice of selecting inverting, noninverting or a combination of inverting and noninverting data paths with 3-state outputs.

The  $S_0$  and  $S_1$  inputs select the bus from which data are to be transferred. The  $\bar{G}$  inputs enable the bus or buses to which data are to be transferred. The port for any bus selected for input and any other bus not enabled for output will be at high impedance.

### Features

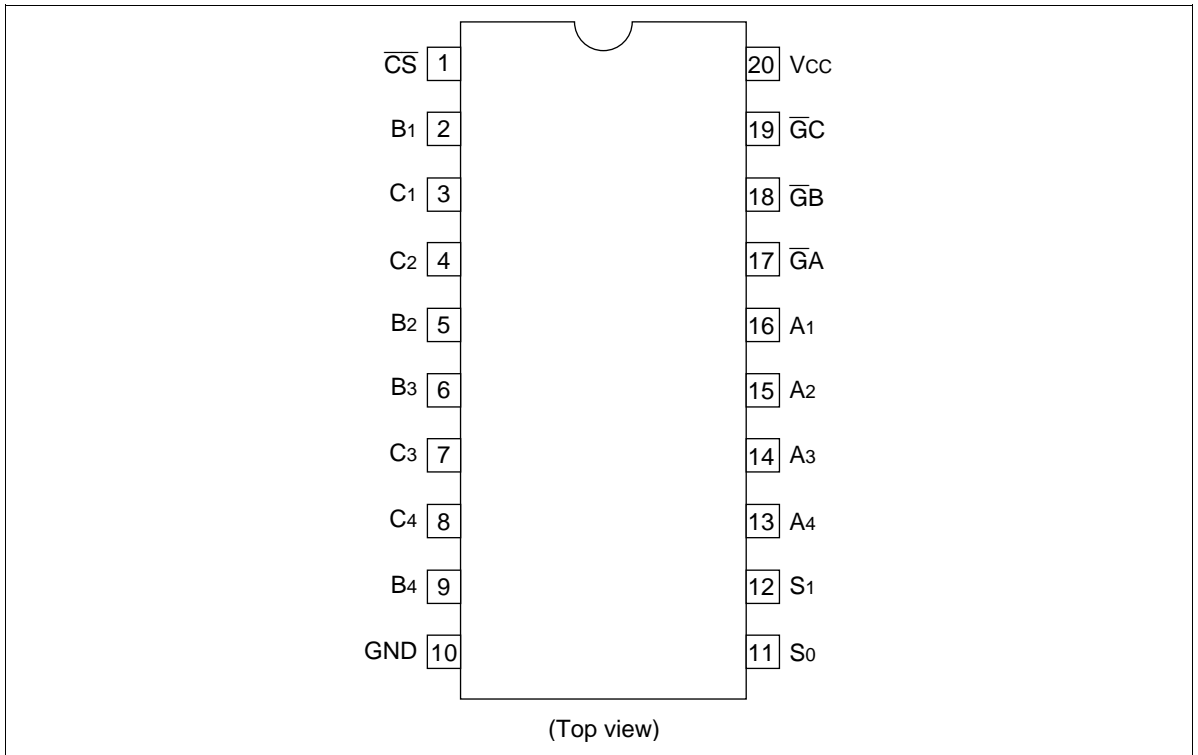
- High Speed Operation
- High Output Current: Fanout of 15 LSTTL Loads
- Wide Operating Voltage:  $V_{CC} = 2$  to 6 V
- Low Input Current: 1  $\mu$ A max
- Low Quiescent Supply Current:  $I_{CC}$  (static) = 4  $\mu$ A max ( $T_a = 25^\circ\text{C}$ )

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## Function Table

Inputs			Transfers Between Buses					
$\overline{CS}$	$S_1$	$S_0$	$\overline{GA}$	$\overline{GB}$	$\overline{GC}$	HD74HC442	HD74HC443	HD74HC444
H	X	X	X	X	X	None	None	None
X	H	H	X	X	X	None	None	None
X	X	X	H	H	H	None	None	None
X	L	L	X	H	H	None	None	None
X	L	H	H	X	H	None	None	None
X	H	L	H	H	X	None	None	None
L	L	L	X	L	L	$A \rightarrow B, A \rightarrow C$	$\overline{A} \rightarrow B, \overline{A} \rightarrow C$	$\overline{A} \rightarrow B, \overline{A} \rightarrow C$
L	L	H	L	X	L	$B \rightarrow C, B \rightarrow A$	$\overline{B} \rightarrow C, \overline{B} \rightarrow A$	$B \rightarrow C, \overline{B} \rightarrow A$
L	H	L	L	L	X	$C \rightarrow A, C \rightarrow B$	$\overline{C} \rightarrow A, \overline{C} \rightarrow B$	$\overline{C} \rightarrow A, C \rightarrow B$
L	L	L	X	L	H	$A \rightarrow B$	$\overline{A} \rightarrow B$	$\overline{A} \rightarrow B$
L	L	H	H	X	L	$B \rightarrow C$	$\overline{B} \rightarrow C$	$B \rightarrow C$
L	H	L	L	H	X	$C \rightarrow A$	$\overline{C} \rightarrow A$	$\overline{C} \rightarrow A$
L	L	L	X	H	L	$A \rightarrow C$	$\overline{A} \rightarrow C$	$\overline{A} \rightarrow C$
L	L	H	L	X	H	$B \rightarrow A$	$\overline{B} \rightarrow A$	$\overline{B} \rightarrow A$
L	H	L	H	L	X	$C \rightarrow B$	$\overline{C} \rightarrow B$	$C \rightarrow B$

Pin Arrangement



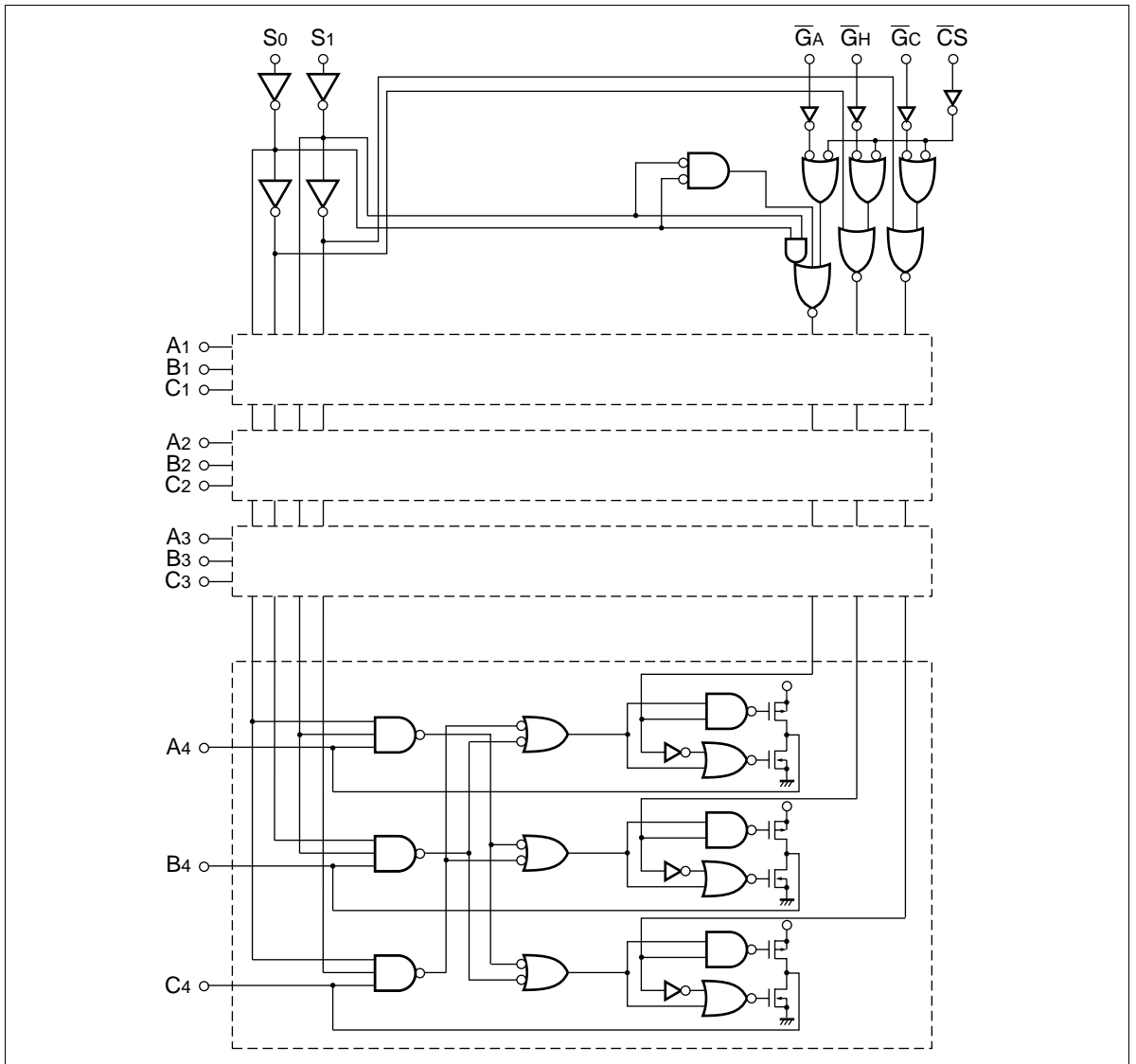
Absolute Maximum Ratings

Item	Symbol	Rating	Unit
Supply voltage range	$V_{CC}$	-0.5 to +7.0	V
Input voltage	$V_{IN}$	-0.5 to $V_{CC} + 0.5$	V
Output voltage	$V_{OUT}$	-0.5 to $V_{CC} + 0.5$	V
Output current	$I_{OUT}$	$\pm 35$	mA
DC current drain per $V_{CC}$ GND	$I_{CC}, I_{GND}$	$\pm 75$	mA
DC input diode current	$I_{IK}$	$\pm 20$	mA
DC output diode current	$I_{OK}$	$\pm 20$	mA
Power Dissipation per package	$P_T$	500	mW
Storage temperature	Tstg	-65 to +150	$^{\circ}C$

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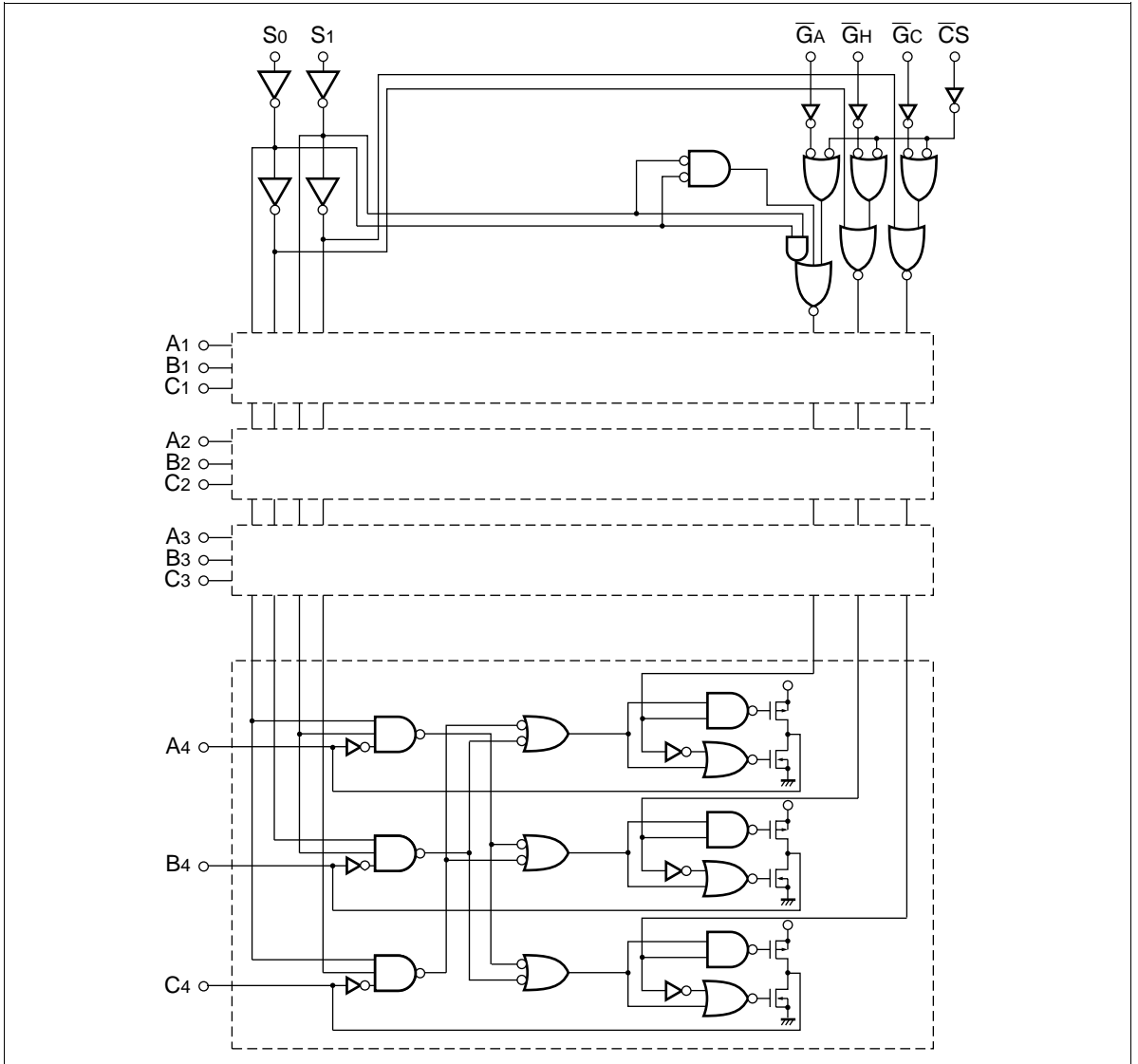
## Logic Diagram

### HD74HC442

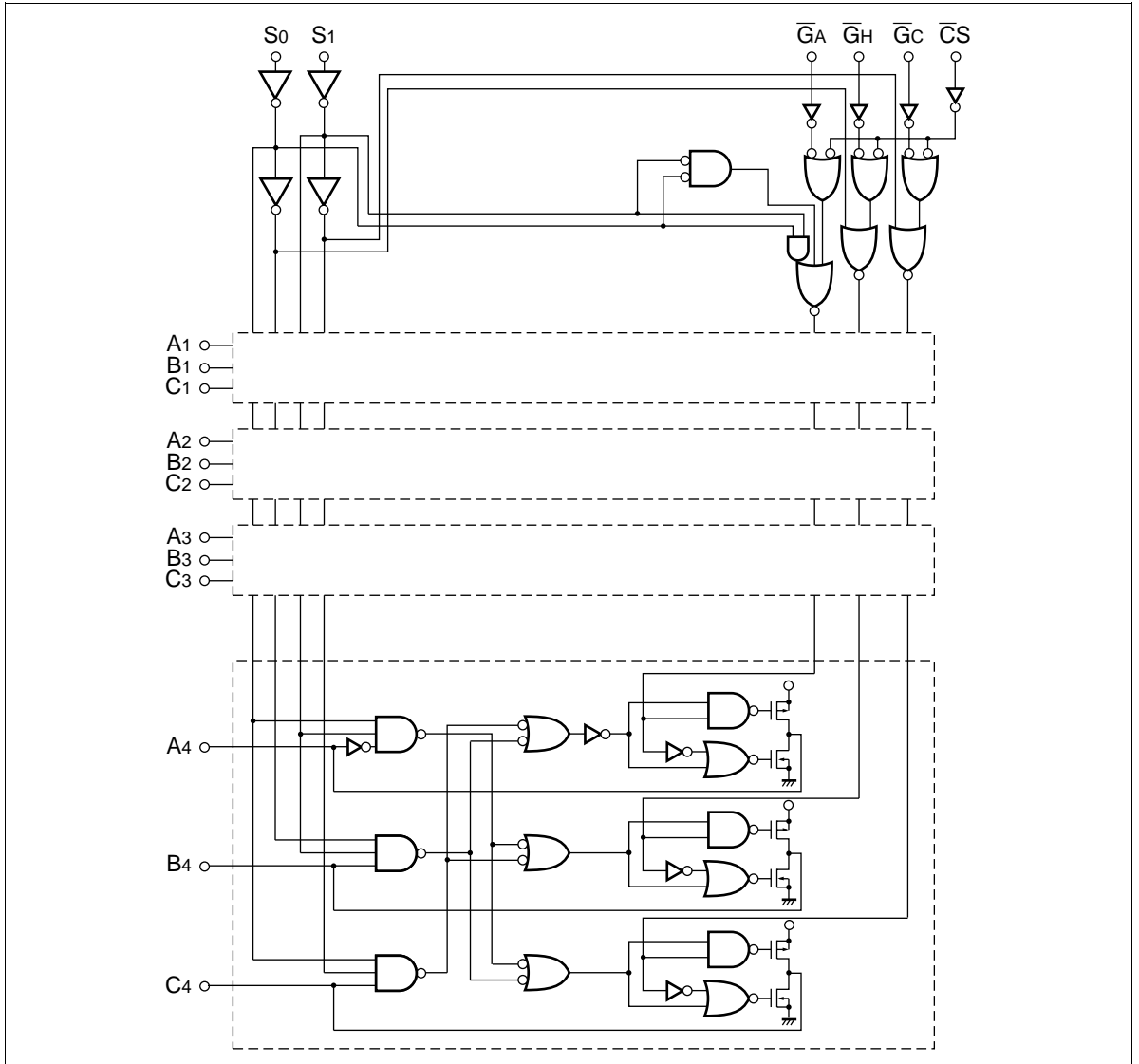


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**DC Characteristics**

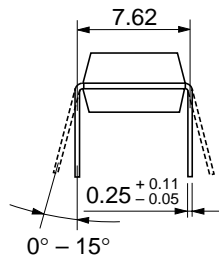
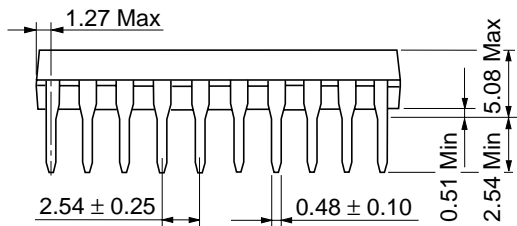
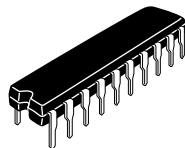
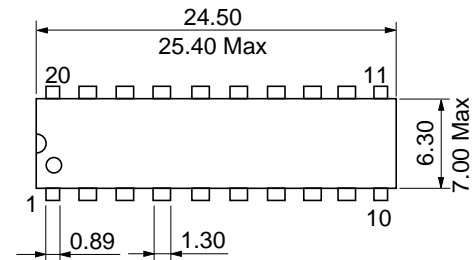
Item	Symbol	V <sub>CC</sub> (V)	Ta = 25°C		Ta = -40 to +85°C		Unit	Test Conditions	
			Min	Typ	Max	Min			Max
Input voltage	V <sub>IH</sub>	2.0	1.5	—	—	1.5	—	V	
		4.5	3.15	—	—	3.15	—		
		6.0	4.2	—	—	4.2	—		
	V <sub>IL</sub>	2.0	—	—	0.5	—	0.5		V
		4.5	—	—	1.35	—	1.35		
		6.0	—	—	1.8	—	1.8		
Output voltage	V <sub>OH</sub>	2.0	1.9	2.0	—	1.9	—	Vin = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OH</sub> = -20 μA	
		4.5	4.4	4.5	—	4.4	—		
		6.0	5.9	6.0	—	5.9	—		
		4.5	4.18	—	—	4.13	—		I <sub>OH</sub> = -6 mA
		6.0	5.68	—	—	5.63	—		I <sub>OH</sub> = -7.8 mA
	V <sub>OL</sub>	2.0	—	0.0	0.1	—	0.1	Vin = V <sub>IH</sub> or V <sub>IL</sub> I <sub>OL</sub> = 20 μA	
		4.5	—	0.0	0.1	—	0.1		
		6.0	—	0.0	0.1	—	0.1		
		4.5	—	—	0.26	—	0.33		I <sub>OL</sub> = 6 mA
		6.0	—	—	0.26	—	0.33		I <sub>OL</sub> = 7.8 mA
Off-state output current	I <sub>OZ</sub>	6.0	—	—	±0.5	—	±5.0	μA	Vin = V <sub>IH</sub> or V <sub>IL</sub> , Vout = V <sub>CC</sub> or GND
Input current	I <sub>in</sub>	6.0	—	—	±0.1	—	±1.0	μA	Vin = V <sub>CC</sub> or GND
Quiescent supply current	I <sub>CC</sub>	6.0	—	—	4.0	—	40	μA	Vin = V <sub>CC</sub> or GND, Iout = 0 μA

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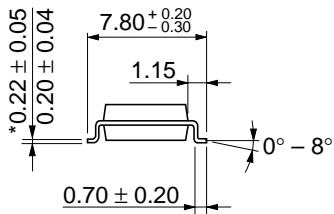
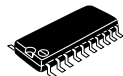
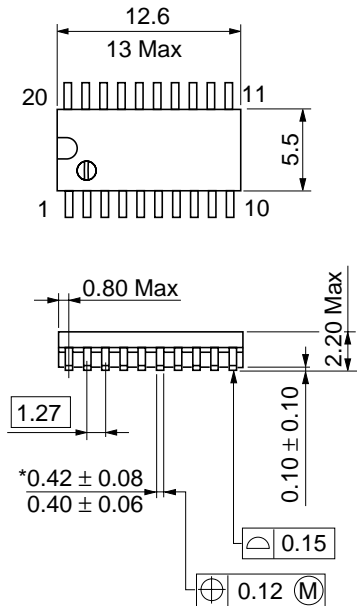
AC Characteristics ( $C_L = 50$  pF, Input  $t_r = t_f = 6$  ns)

Item	Symbol	$V_{CC}$ (V)	$T_a = 25^\circ\text{C}$			$T_a = -40$ to $+85^\circ\text{C}$		Unit	Test Conditions
			Min	Typ	Max	Min	Max		
Propagation delay time	$t_{PLH}$	2.0	—	—	200	—	250	ns	
	$t_{PHL}$	4.5	—	—	40	—	50		
		6.0	—	—	34	—	43		
Output enable time	$t_{ZH}$	2.0	—	—	150	—	190	ns	
	$t_{ZL}$	4.5	—	—	30	—	38		
		6.0	—	—	26	—	33		
Output disable time	$t_{HZ}$	2.0	—	—	150	—	190	ns	
	$t_{LZ}$	4.5	—	—	30	—	38		
		6.0	—	—	26	—	33		
Output rise/fall time	$t_{TLH}$	2.0	—	—	60	—	75	ns	
	$t_{THL}$	4.5	—	—	12	—	15		
		6.0	—	—	10	—	13		
Input capacitance	$C_{in}$	—	—	5	10	—	10	pF	



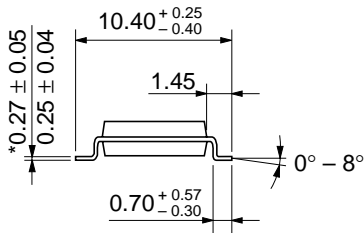
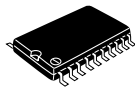
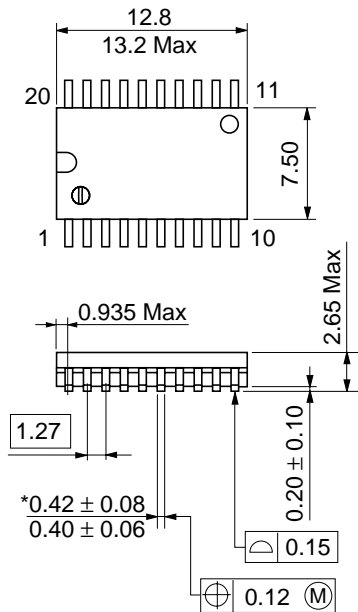


Hitachi Code	DP-20N
JEDEC	—
EIAJ	Conforms
Weight (reference value)	1.26 g



Hitachi Code	FP-20DA
JEDEC	—
EIAJ	Conforms
Weight (reference value)	0.31 g

\*Dimension including the plating thickness  
Base material dimension



Hitachi Code	FP-20DB
JEDEC	Conforms
EIAJ	—
Weight (reference value)	0.52 g

\*Dimension including the plating thickness  
 Base material dimension

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